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INFORMATION DISCLOSURE STATEMENT
 BY APPLICANT



Date: November 30, 2001

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Applicant: ASADA

Appln. No.: 09/922,918

Filing Date: August 7, 2001

Examiner:

Group Art Unit: 2838

U.S. PATENT DOCUMENTS

Examiner's Initials*		Document Number	Date MM/YYYY	Name (Family Name of First Inventor)	Class	Sub Class	Filing Date (if appropriate)
JJ	AR	5,936,440	08/1999	ASADA et al.	327	110	
	BR						
	CR						
	DR						
	ER						
	FR						
	GR						
	HR						
	IR						
	JR						
	KR						
	LR						
	MR						
	NR						

FOREIGN PATENT DOCUMENTS

		Document Number	Date MM/YYYY	Country	Inventor Name	English Abstract		Translation Readily Available	
						Enclosed	No	Enclose	No
JJ	OR	WO 00/27032	05/2000	GERMANY	MAGRUDER et al	x		x	
JJ	PR	DE 19755653	07/1998	GERMANY	NAOYUKI et al	x			x
JJ	QR	06022470	01/1994	JAPAN	YUJI	x			x
JJ	RR	0 678983 A1	10/1995	EUROPE	PENZA	x		x	
JJ	SR	GB 2318467	04/1998	UK	CLEMENTE	x		x	
	TR								
	UR								
	VR								
	WR								
	XR								

OTHER (Including in this order Author, Title, Periodical Name, Date, Pertinent Pages, etc.)

JJ	YR	H.P. Yee, Ph.D., "An EMI Suppression MOSFET Driver, IEEE, 1997, pp. 242-248
	ZR	
	AAR	
	BBR	
	CCR	
	DDR	

Examiner Julio Gonzalez

Date Considered: 03/18/03

*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.